

MC74VHC595

8-Bit Shift Register with Output Storage Register (3-State)

The MC74VHC595 is an advanced high speed 8-bit shift register with an output storage register fabricated with silicon gate CMOS technology.

It achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining CMOS low power dissipation.

The MC74VHC595 contains an 8-bit static shift register which feeds an 8-bit storage register.

Shift operation is accomplished on the positive going transition of the Shift Clock input (SCK). The output register is loaded with the contents of the shift register on the positive going transition of the Register Clock input (RCK). Since the RCK and SCK signals are independent, parallel outputs can be held stable during the shift operation. And, since the parallel outputs are 3-state, the VHC595 can be directly connected to an 8-bit bus. This register can be used in serial-to-parallel conversion, data receivers, etc.

The internal circuit is composed of three stages, including a buffer output which provides high noise immunity and stable output. The inputs tolerate voltages up to 7V, allowing the interface of 5V systems to 3V systems.

Features

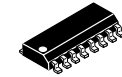
- High Speed: $f_{max} = 185\text{MHz}$ (Typ) at $V_{CC} = 5\text{V}$
- Low Power Dissipation: $I_{CC} = 4\mu\text{A}$ (Max) at $T_A = 25^\circ\text{C}$
- High Noise Immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$
- Power Down Protection Provided on Inputs
- Balanced Propagation Delays
- Designed for 2V to 5.5V Operating Range
- Low Noise: $V_{OLP} = 1.0\text{V}$ (Max)
- Pin and Function Compatible with Other Standard Logic Families
- Latchup Performance Exceeds 300mA
- ESD Performance: HBM > 2000V; Machine Model > 200V
- These are Pb-Free Devices



ON Semiconductor®

<http://onsemi.com>

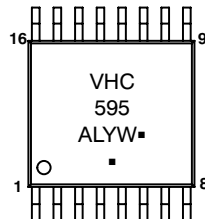
MARKING DIAGRAMS



SOIC-16
D SUFFIX
CASE 751B

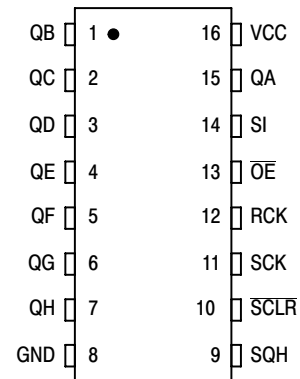


TSSOP-16
DT SUFFIX
CASE 948F



A = Assembly Location
WL = Wafer Lot
Y = Year
W, WW = Work Week
G or ■ = Pb-Free Package
(Note: Microdot may be in either location)

PIN ASSIGNMENT



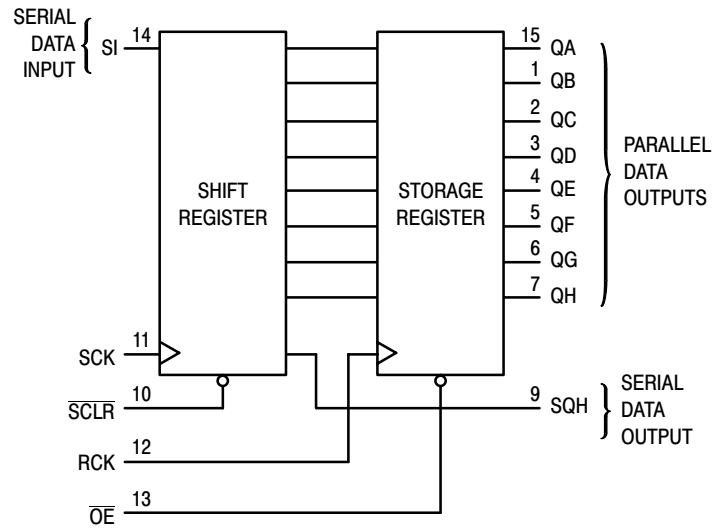
ORDERING INFORMATION

| Device | Package | Shipping† |
|-----------------|--------------------|------------------|
| MC74VHC595DR2G | SOIC-16 (Pb-Free) | 2500 Tape & Reel |
| MC74VHC595DTR2G | TSSOP-16 (Pb-Free) | 2500 Tape & Reel |

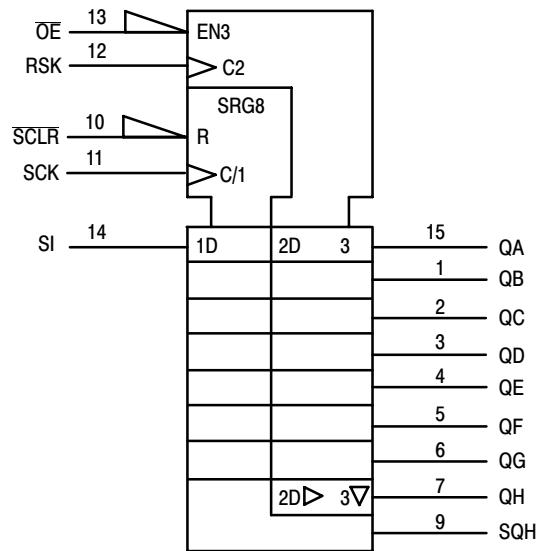
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

MC74VHC595

LOGIC DIAGRAM

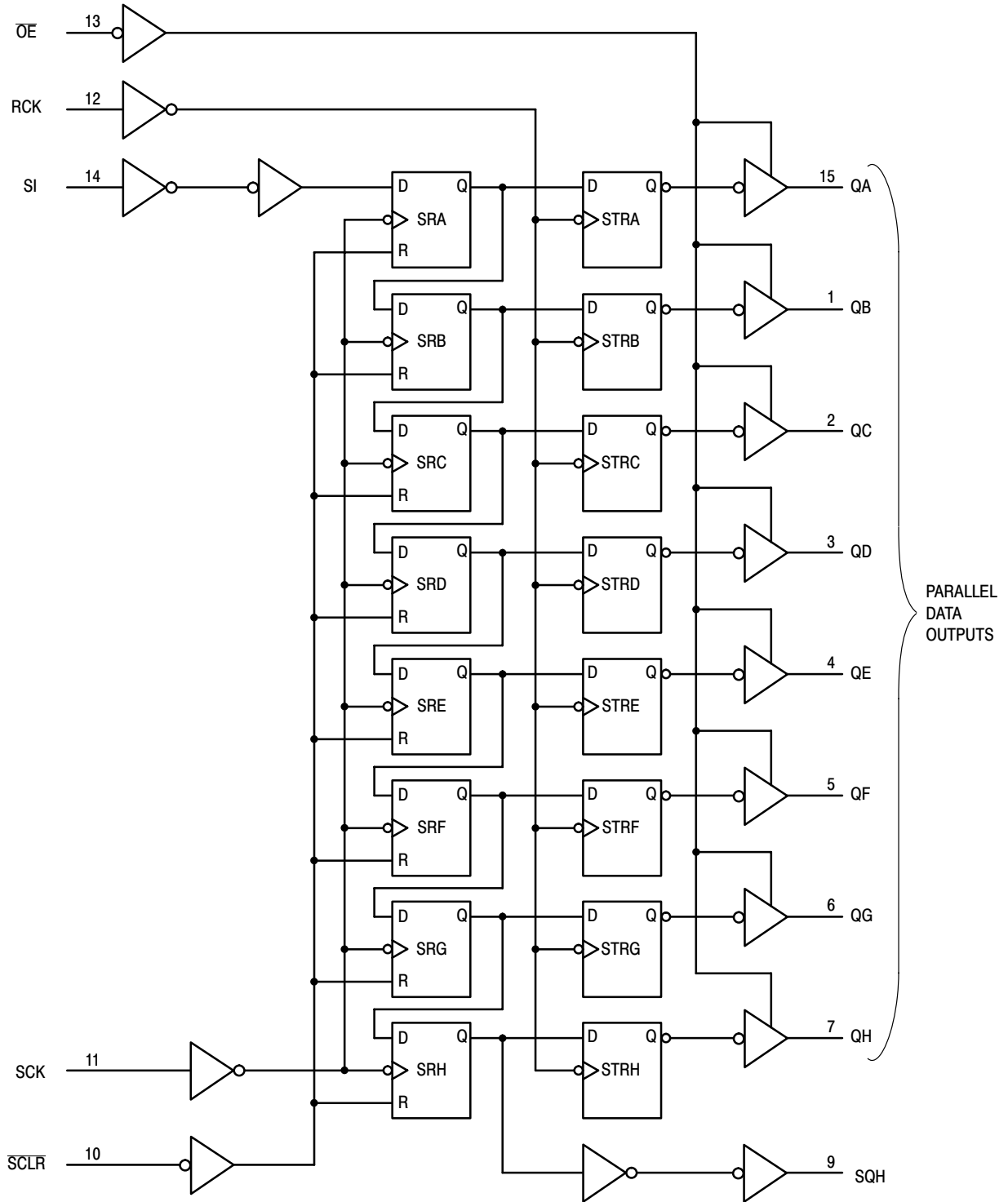


IEC LOGIC SYMBOL



MC74VHC595

EXPANDED LOGIC DIAGRAM



MC74VHC595

FUNCTION TABLE

| Operation | Inputs | | | | | Resulting Function | | | |
|--|--------------|-------------------|-------------------|-----------------|--------------------|--|------------------------------------|-----------------------------------|----------------------------|
| | Reset (SCLR) | Serial Input (SI) | Shift Clock (SCK) | Reg Clock (RCK) | Output Enable (OE) | Shift Register Contents | Storage Register Contents | Serial Output (SQH) | Parallel Outputs (QA – QH) |
| Clear shift register | L | X | X | L, H, ↓ | L | L | U | L | U |
| Shift data into shift register | H | D | ↑ | L, H, ↓ | L | D → SR _A ; SR _N → SR _{N+1} | U | SR _G → SR _H | U |
| Registers remains unchanged | H | X | L, H, ↓ | X | L | U | ** | U | ** |
| Transfer shift register contents to storage register | H | X | L, H, ↓ | ↑ | L | U | SR _N → STR _N | * | SR _N |
| Storage register remains unchanged | X | X | X | L, H, ↓ | L | * | U | * | U |
| Enable parallel outputs | X | X | X | X | L | * | ** | * | Enabled |
| Force outputs into high impedance state | X | X | X | X | H | * | ** | * | Z |

SR = shift register contents D = data (L, H) logic level ↓ = High-to-Low * = depends on Reset and Shift Clock inputs

STR = storage register contents U = remains unchanged ↑ = Low-to-High ** = depends on Register Clock input

MAXIMUM RATINGS*

| Symbol | Parameter | Value | Unit |
|------------------|--|--------------------------------|------|
| V _{CC} | DC Supply Voltage | - 0.5 to + 7.0 | V |
| V _{in} | DC Input Voltage | - 0.5 to + 7.0 | V |
| V _{out} | DC Output Voltage | - 0.5 to V _{CC} + 0.5 | V |
| I _{IK} | Input Diode Current | - 20 | mA |
| I _{OK} | Output Diode Current | ± 20 | mA |
| I _{out} | DC Output Current, per Pin | ± 25 | mA |
| I _{CC} | DC Supply Current, V _{CC} and GND Pins | ± 50 | mA |
| P _D | Power Dissipation in Still Air, SOIC Packages† TSSOP Package† | 500 450 | mW |
| T _{stg} | Storage Temperature | - 65 to + 150 | °C |

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range GND ≤ (V_{in} or V_{out}) ≤ V_{CC}. Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

* Absolute maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute-maximum-rated conditions is not implied.

† Derating — SOIC Packages: - 7 mW/°C from 65° to 125° C
TSSOP Package: - 6.1 mW/°C from 65° to 125° C

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Min | Max | Unit |
|---------------------------------|--|------|-----------------|------|
| V _{CC} | DC Supply Voltage | 2.0 | 5.5 | V |
| V _{in} | DC Input Voltage | 0 | 5.5 | V |
| V _{out} | DC Output Voltage | 0 | V _{CC} | V |
| T _A | Operating Temperature, All Package Types | - 55 | + 125 | °C |
| t _r , t _f | Input Rise and Fall Time V _{CC} = 3.3V ± 0.3V V _{CC} = 5.0V ± 0.5V | 0 | 100 20 | ns/V |

MC74VHC595

The θ_{JA} of the package is equal to 1/Derating. Higher junction temperatures may affect the expected lifetime of the device per the table and figure below.

DEVICE JUNCTION TEMPERATURE VERSUS TIME TO 0.1% BOND FAILURES

| Junction Temperature °C | Time, Hours | Time, Years |
|-------------------------|-------------|-------------|
| 80 | 1,032,200 | 117.8 |
| 90 | 419,300 | 47.9 |
| 100 | 178,700 | 20.4 |
| 110 | 79,600 | 9.4 |
| 120 | 37,000 | 4.2 |
| 130 | 17,800 | 2.0 |
| 140 | 8,900 | 1.0 |

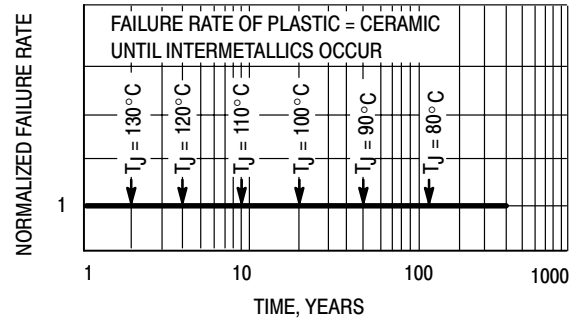


Figure 1. Failure Rate vs. Time Junction Temperature

DC ELECTRICAL CHARACTERISTICS

| Symbol | Parameter | Test Conditions | V _{CC} (V) | T _A = 25°C | | | T _A = ≤ 85°C | | T _A = ≤ 125°C | | Unit |
|-----------------|---|--|--------------------------|----------------------------|-------------------|-----------------------------|-----------------------------|-------------------|-----------------------------|-----|------|
| | | | | Min | Typ | Max | Min | Max | Min | Max | |
| V _{IH} | Minimum High-Level Input Voltage | | 2.0 3.0 4.5 5.5 | 1.5 2.1 3.15 3.85 | | | 1.5 2.1 3.15 3.85 | | 1.5 2.1 3.15 3.85 | V | |
| V _{IL} | Maximum Low-Level Input Voltage | | 2.0 3.0 4.5 5.5 | | | 0.59 0.9 1.35 1.65 | 0.59 0.9 1.35 1.65 | | 0.59 0.9 1.35 1.65 | V | |
| V _{OH} | Minimum High-Level Output Voltage V _{IN} = V _{IH} or V _{IL} | V _{IN} = V _{IH} or V _{IL} I _{OH} = -50 μA | 2.0 3.0 4.5 | 1.9 2.9 4.4 | 2.0 3.0 4.5 | | 1.9 2.9 4.4 | | 1.9 2.9 4.4 | V | |
| | | V _{IN} = V _{IH} or V _{IL} I _{OH} = -4 mA I _{OH} = -8 mA | 3.0 4.5 | 2.58 3.94 | | | 2.48 3.80 | | 2.34 3.66 | | |
| V _{OL} | Maximum Low-Level Output Voltage V _{IN} = V _{IH} or V _{IL} | V _{IN} = V _{IH} or V _{IL} I _{OL} = 50 μA | 2.0 3.0 4.5 | | 0.0 0.0 0.0 | 0.1 0.1 0.1 | | 0.1 0.1 0.1 | 0.1 0.1 0.1 | V | |
| | | V _{IN} = V _{IH} or V _{IL} I _{OL} = 4 mA I _{OL} = 8 mA | 3.0 4.5 | | | 0.36 0.36 | | 0.44 0.44 | 0.52 0.52 | | |
| I _{IN} | Maximum Input Leakage Current | V _{IN} = 5.5 V or GND | 0 to 5.5 | | | ± 0.1 | | ± 1.0 | ± 1.0 | μA | |
| I _{CC} | Maximum Quiescent Supply Current | V _{IN} = V _{CC} or GND | 5.5 | | | 4.0 | | 40.0 | 40.0 | μA | |
| I _{OZ} | Three-State Output Off-State Current | V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND | 5.5 | | | ± 0.25 | | ± 2.5 | ± 2.5 | μA | |

MC74VHC595

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0\text{ns}$)

| Symbol | Parameter | Test Conditions | $T_A = 25^\circ\text{C}$ | | | $T_A = \leq 85^\circ\text{C}$ | | $T_A = \leq 125^\circ\text{C}$ | | Unit |
|----------------------------------|--|---|--------------------------|------|------|-------------------------------|------|--------------------------------|------|------|
| | | | Min | Typ | Max | Min | Max | Min | Max | |
| f_{max} | Maximum Clock Frequency (50% Duty Cycle) | $V_{\text{CC}} = 3.3 \pm 0.3\text{ V}$ | 80 | 150 | | 70 | | 70 | | MHz |
| | | $V_{\text{CC}} = 5.0 \pm 0.5\text{ V}$ | 135 | 185 | | 115 | | 115 | | |
| $t_{\text{PLH}}, t_{\text{PHL}}$ | Propagation Delay, SCK to SQH | $V_{\text{CC}} = 3.3 \pm 0.3\text{ V}$ $C_L = 15\text{pF}$ | | 8.8 | 13.0 | 1.0 | 15.0 | 1.0 | 15.0 | ns |
| | | $V_{\text{CC}} = 3.3 \pm 0.3\text{ V}$ $C_L = 50\text{pF}$ | | 11.3 | 16.5 | 1.0 | 18.5 | 1.0 | 18.5 | |
| t_{PHL} | Propagation Delay, CPLR to SQH | $V_{\text{CC}} = 5.0 \pm 0.5\text{ V}$ $C_L = 15\text{pF}$ | | 6.2 | 8.2 | 1.0 | 9.4 | 1.0 | 9.4 | ns |
| | | $V_{\text{CC}} = 5.0 \pm 0.5\text{ V}$ $C_L = 50\text{pF}$ | | 7.7 | 10.2 | 1.0 | 11.4 | 1.0 | 11.4 | |
| t_{PHL} | Propagation Delay, RCK to QA-QH | $V_{\text{CC}} = 3.3 \pm 0.3\text{ V}$ $C_L = 15\text{pF}$ | | 7.7 | 11.9 | 1.0 | 13.5 | 1.0 | 13.5 | ns |
| | | $V_{\text{CC}} = 3.3 \pm 0.3\text{ V}$ $C_L = 50\text{pF}$ | | 10.2 | 15.4 | 1.0 | 17.0 | 1.0 | 17.0 | |
| $t_{\text{PZH}}, t_{\text{PZL}}$ | Output Enable Time, OE to QA-QH | $V_{\text{CC}} = 5.0 \pm 0.5\text{ V}$ $R_L = 1\text{ k}\Omega$ $C_L = 15\text{pF}$ | | 5.4 | 7.4 | 1.0 | 8.5 | 1.0 | 8.5 | ns |
| | | $V_{\text{CC}} = 5.0 \pm 0.5\text{ V}$ $R_L = 1\text{ k}\Omega$ $C_L = 50\text{pF}$ | | 6.9 | 9.4 | 1.0 | 10.5 | 1.0 | 10.5 | |
| $t_{\text{PZH}}, t_{\text{PZL}}$ | Output Disable Time, OE to QA-QH | $V_{\text{CC}} = 3.3 \pm 0.3\text{ V}$ $C_L = 15\text{pF}$ | | 7.5 | 11.5 | 1.0 | 13.5 | 1.0 | 13.5 | ns |
| | | $V_{\text{CC}} = 3.3 \pm 0.3\text{ V}$ $C_L = 50\text{pF}$ | | 9.0 | 15.0 | 1.0 | 17.0 | 1.0 | 17.0 | |
| $t_{\text{PLZ}}, t_{\text{PHZ}}$ | Output Disable Time, OE to QA-QH | $V_{\text{CC}} = 5.0 \pm 0.5\text{ V}$ $R_L = 1\text{ k}\Omega$ $C_L = 15\text{pF}$ | | 4.8 | 8.6 | 1.0 | 10.0 | 1.0 | 10.0 | ns |
| | | $V_{\text{CC}} = 5.0 \pm 0.5\text{ V}$ $R_L = 1\text{ k}\Omega$ $C_L = 50\text{pF}$ | | 8.3 | 10.6 | 1.0 | 12.0 | 1.0 | 12.0 | |
| $t_{\text{PLZ}}, t_{\text{PHZ}}$ | Output Disable Time, OE to QA-QH | $V_{\text{CC}} = 3.3 \pm 0.3\text{ V}$ $C_L = 50\text{pF}$ | | 12.1 | 15.7 | 1.0 | 16.2 | 1.0 | 16.2 | ns |
| | | $V_{\text{CC}} = 5.0 \pm 0.5\text{ V}$ $C_L = 50\text{pF}$ | | 7.6 | 10.3 | 1.0 | 11.0 | 1.0 | 11.0 | |
| C_{IN} | Input Capacitance | | | 4 | 10 | | 10 | | 10 | pF |
| C_{OUT} | Three-State Output Capacitance (Output in High-Impedance State), QA-QH | | | 6 | | | 10 | | 10 | pF |

| C_{PD} | Power Dissipation Capacitance (Note 1) | Typical @ 25°C , $V_{\text{CC}} = 5.0\text{V}$ | | pF |
|-----------------|--|--|-----|----|
| | | Min | Max | |
| | | | 87 | |

1. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: $I_{\text{CC(OPR)}} = C_{\text{PD}} \cdot V_{\text{CC}} \cdot f_{\text{in}} + I_{\text{CC}}$. C_{PD} is used to determine the no-load dynamic power consumption; $P_{\text{D}} = C_{\text{PD}} \cdot V_{\text{CC}}^2 \cdot f_{\text{in}} + I_{\text{CC}} \cdot V_{\text{CC}}$.

NOISE CHARACTERISTICS (Input $t_r = t_f = 3.0\text{ns}$, $C_L = 50\text{pF}$, $V_{\text{CC}} = 5.0\text{V}$)

| Symbol | Characteristic | $T_A = 25^\circ\text{C}$ | | Unit |
|------------------|--|--------------------------|-------|------|
| | | Typ | Max | |
| V_{OLP} | Quiet Output Maximum Dynamic V_{OL} | 0.8 | 1.0 | V |
| V_{OLV} | Quiet Output Minimum Dynamic V_{OL} | - 0.8 | - 1.0 | V |
| V_{IHD} | Minimum High Level Dynamic Input Voltage | | 3.5 | V |
| V_{ILD} | Maximum Low Level Dynamic Input Voltage | | 1.5 | V |

MC74VHC595

TIMING REQUIREMENTS (Input $t_r = t_f = 3.0\text{ns}$)

| Symbol | Parameter | V _{CC} V | T _A = 25°C | | T _A = - 40 to 85°C | T _A = - 55 to 125°C | Unit |
|--------------------|--|----------------------|-----------------------|------------|----------------------------------|-----------------------------------|------|
| | | | Typ | Limit | Limit | Limit | |
| t _{SU} | Setup Time, SI to SCK | 3.3 5.0 | | 3.5 3.0 | 3.5 3.0 | 3.5 3.0 | ns |
| t _{SU(H)} | Setup Time, SCK to RCK | 3.3 5.0 | | 8.0 5.0 | 8.5 5.0 | 8.5 5.0 | ns |
| t _{SU(L)} | Setup Time, $\overline{\text{SCLR}}$ to RCK | 3.3 5.0 | | 8.0 5.0 | 9.0 5.0 | 9.0 5.0 | ns |
| t _H | Hold Time, SI to SCK | 3.3 5.0 | | 1.5 2.0 | 1.5 2.0 | 1.5 2.0 | ns |
| t _{H(L)} | Hold Time, $\overline{\text{SCLR}}$ to RCK | 3.3 5.0 | | 0 0 | 0 0 | 1.0 1.0 | ns |
| t _{REC} | Recovery Time, $\overline{\text{SCLR}}$ to SCK | 3.3 5.0 | | 3.0 2.5 | 3.0 2.5 | 3.0 2.5 | ns |
| t _W | Pulse Width, SCK or RCK | 3.3 5.0 | | 5.0 5.0 | 5.0 5.0 | 5.0 5.0 | ns |
| t _{W(L)} | Pulse Width, $\overline{\text{SCLR}}$ | 3.3 5.0 | | 5.0 5.0 | 5.0 5.0 | 5.0 5.0 | ns |

MC74VHC595

SWITCHING WAVEFORMS

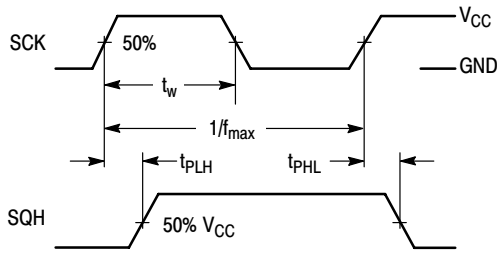


Figure 2.

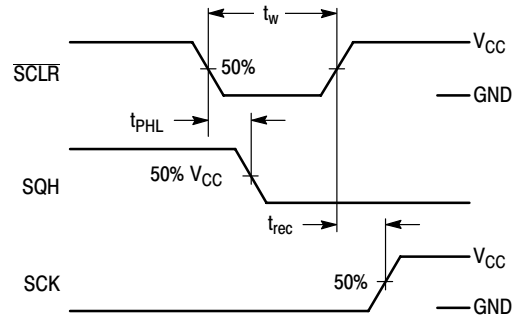


Figure 3.

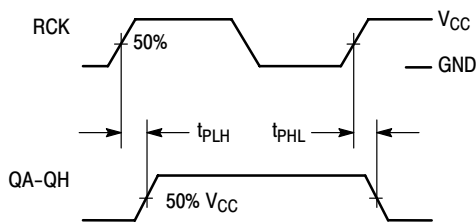


Figure 4.

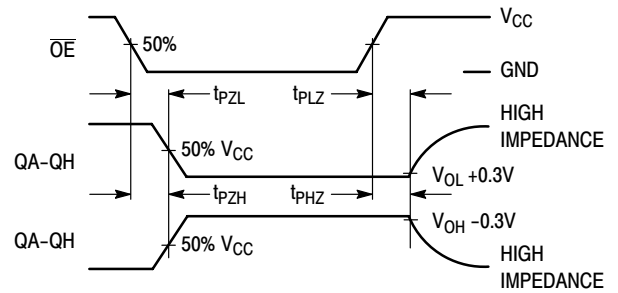


Figure 5.

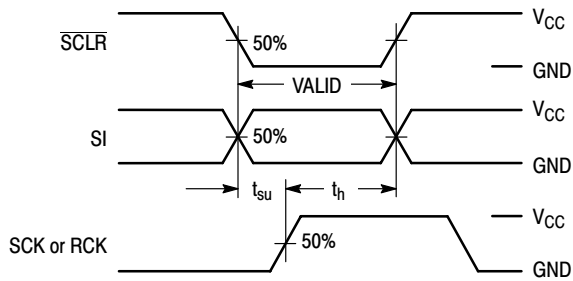


Figure 6.

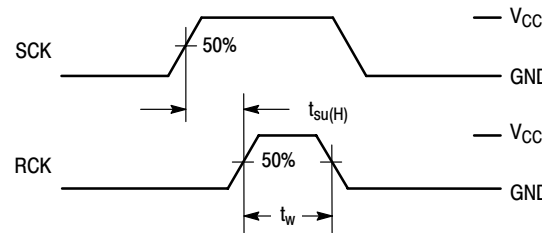
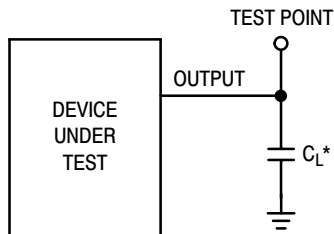


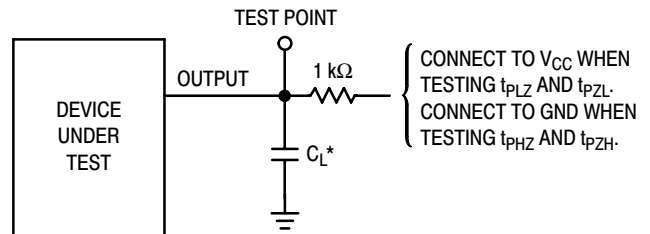
Figure 7.

TEST CIRCUITS



*Includes all probe and jig capacitance

Figure 8.

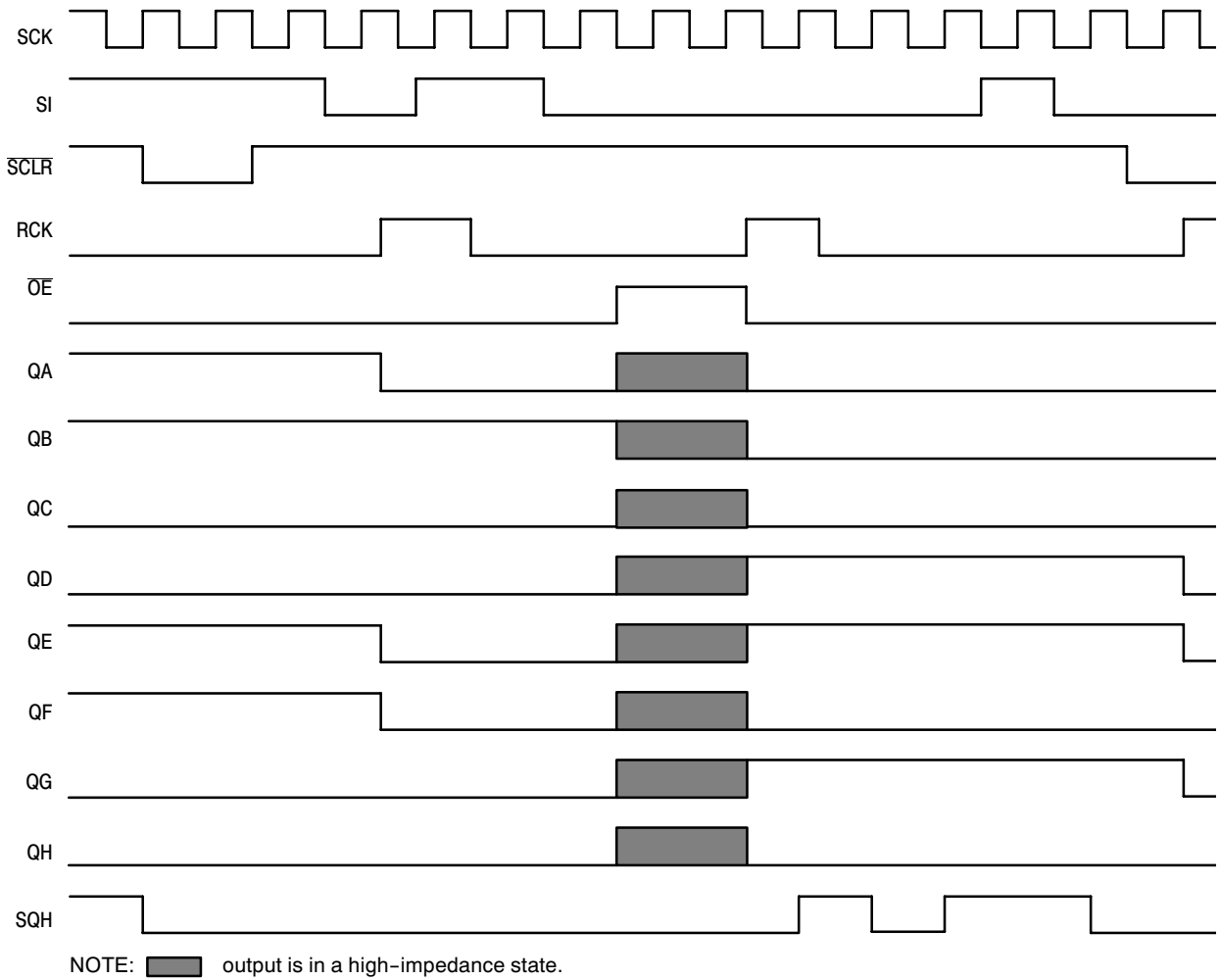


*Includes all probe and jig capacitance

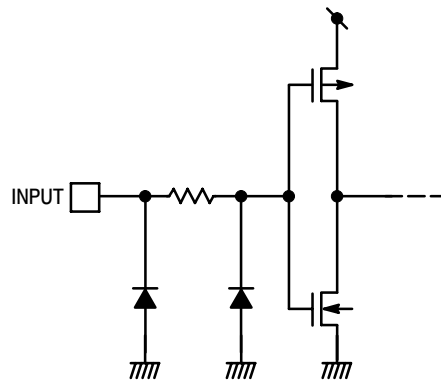
Figure 9.

MC74VHC595

TIMING DIAGRAM



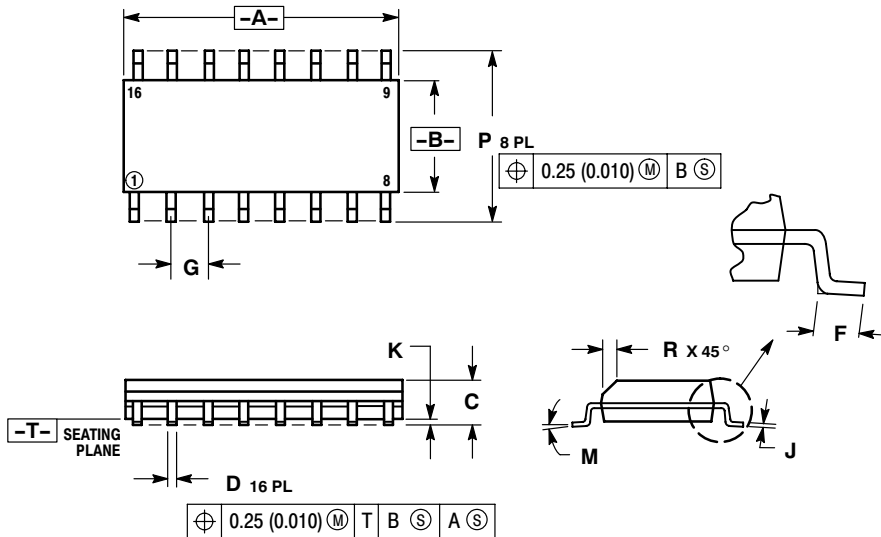
INPUT EQUIVALENT CIRCUIT



MC74VHC595

PACKAGE DIMENSIONS

SOIC-16
CASE 751B-05
ISSUE K

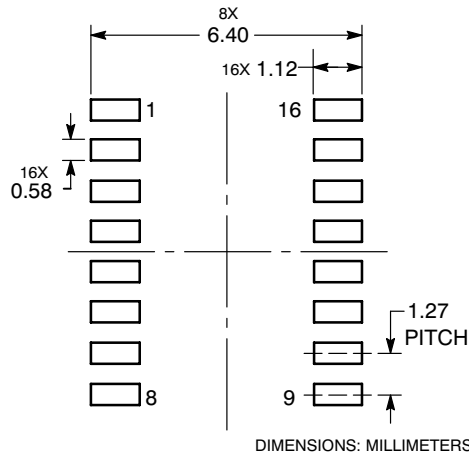


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

| DIM | MILLIMETERS | | INCHES | |
|-----|-------------|-------|-----------|-------|
| | MIN | MAX | MIN | MAX |
| A | 9.80 | 10.00 | 0.386 | 0.393 |
| B | 3.80 | 4.00 | 0.150 | 0.157 |
| C | 1.35 | 1.75 | 0.054 | 0.068 |
| D | 0.35 | 0.49 | 0.014 | 0.019 |
| F | 0.40 | 1.25 | 0.016 | 0.049 |
| G | 1.27 BSC | | 0.050 BSC | |
| J | 0.19 | 0.25 | 0.008 | 0.009 |
| K | 0.10 | 0.25 | 0.004 | 0.009 |
| M | 0° | 7° | 0° | 7° |
| P | 5.80 | 6.20 | 0.229 | 0.244 |
| R | 0.25 | 0.50 | 0.010 | 0.019 |

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
Literature Distribution Center for ON Semiconductor
P.O. Box 5163, Denver, Colorado 80217 USA
Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada
Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada
Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free
USA/Canada
Europe, Middle East and Africa Technical Support:
Phone: 421 33 790 2910
Japan Customer Focus Center
Phone: 81-3-5773-3850

ON Semiconductor Website: www.onsemi.com
Order Literature: <http://www.onsemi.com/orderlit>
For additional information, please contact your local Sales Representative

MC74VHC595/D